

Prediction of high carrier mobility for novel Janus $\text{Mo}_8\text{S}_6\text{Se}_6$ monolayers with different phases: first principles calculations

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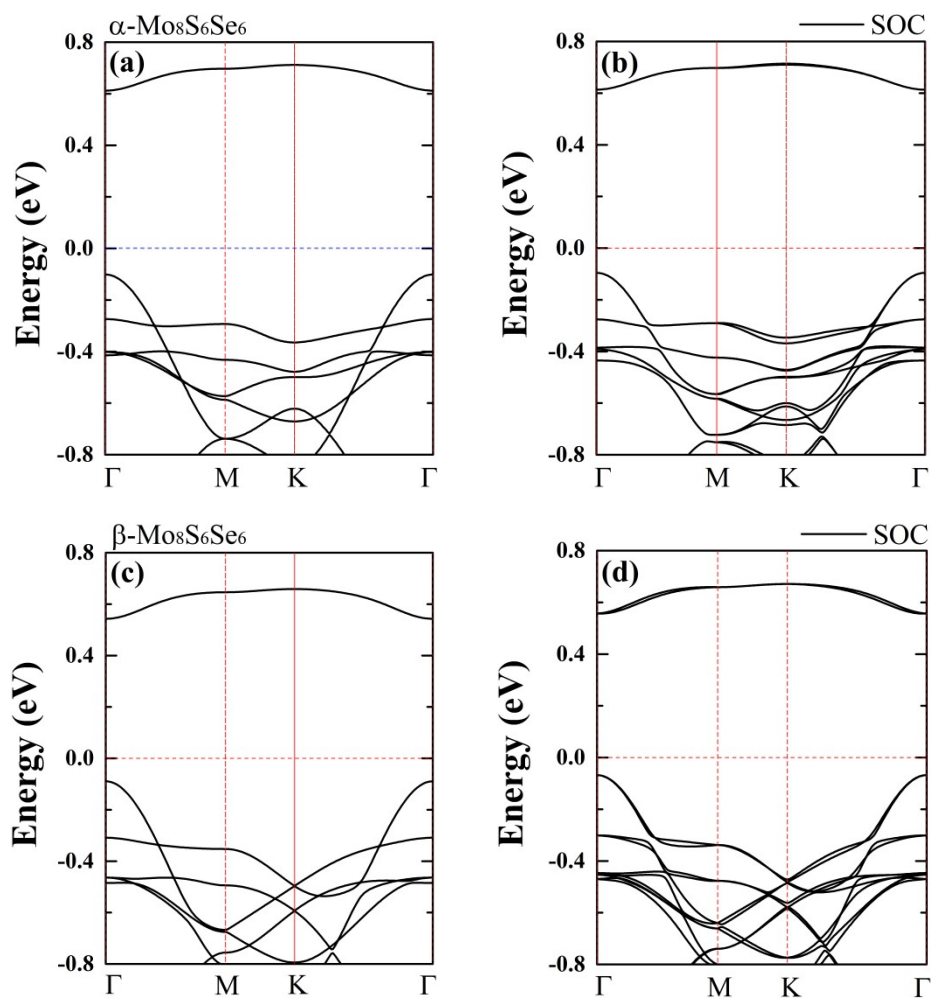


Fig. S1. The energy band structures of Janus $\text{Mo}_8\text{S}_6\text{Se}_6$ monolayers with α - (a, b) and β -phases (c, d) using GGA (a, c) and GGA+SOC (b, d).